

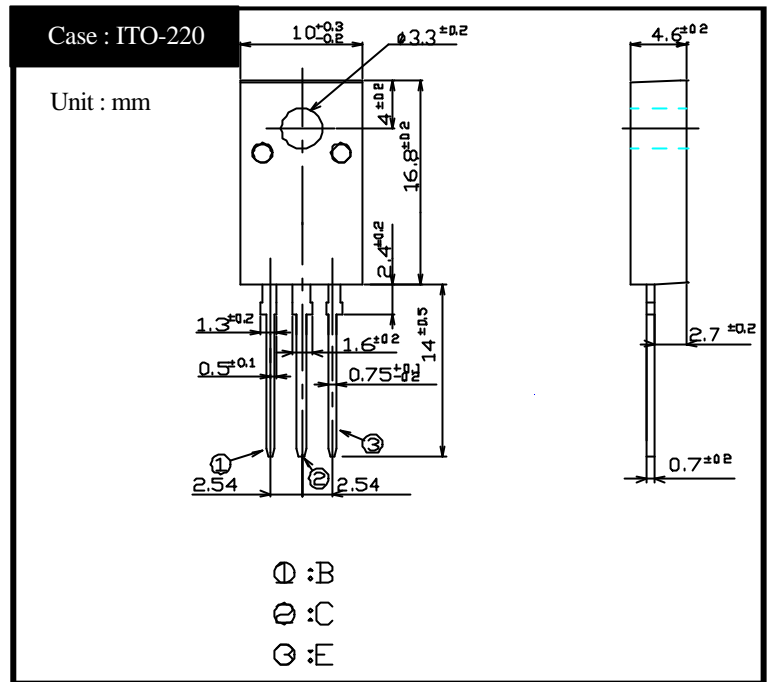
# SHINDENGEN

## Darlington Transistor

**2SD1795**  
(TP10K40)

**10A NPN**

### OUTLINE DIMENSIONS



### RATINGS

#### Absolute Maximum Ratings

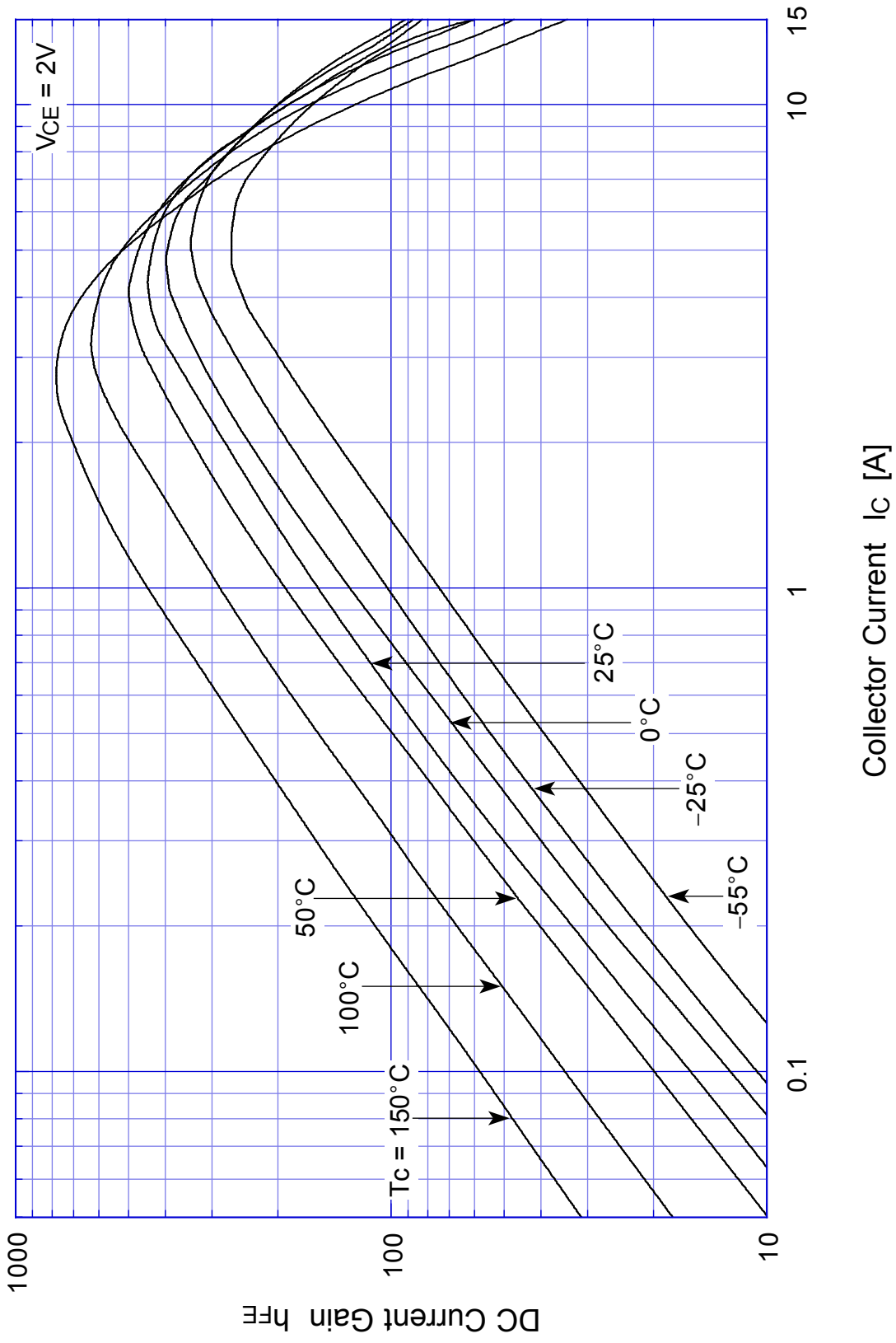
| Item                         | Symbol           | Conditions                     | Ratings    | Unit |
|------------------------------|------------------|--------------------------------|------------|------|
| Storage Temperature          | T <sub>stg</sub> |                                | -55 ~ +150 |      |
| Junction Temperature         | T <sub>j</sub>   |                                | +150       |      |
| Collector to Base Voltage    | V <sub>CB0</sub> |                                | 500        | V    |
| Collector to Emitter Voltage | V <sub>CEO</sub> |                                | 400        | V    |
| Emitter to Base Voltage      | V <sub>EBO</sub> |                                | 12         | V    |
| Collector Current DC         | I <sub>C</sub>   |                                | 10         | A    |
| Collector Current Peak       | I <sub>CP</sub>  |                                | 15         | A    |
| Base Current DC              | I <sub>B</sub>   |                                | 0.5        | A    |
| Base Current Peak            | I <sub>BP</sub>  |                                | 1.0        | A    |
| Total Transistor Dissipation | P <sub>T</sub>   | T <sub>C</sub> = 25            | 50         | W    |
| Dielectric Strength          | V <sub>dis</sub> | Terminals to case AC 1 minute  | 2          | kV   |
| Mounting Torque              | TOR              | (Recommended torque : 0.3N·m ) | 0.5        | N·m  |

#### Electrical Characteristics (T<sub>C</sub>=25 )

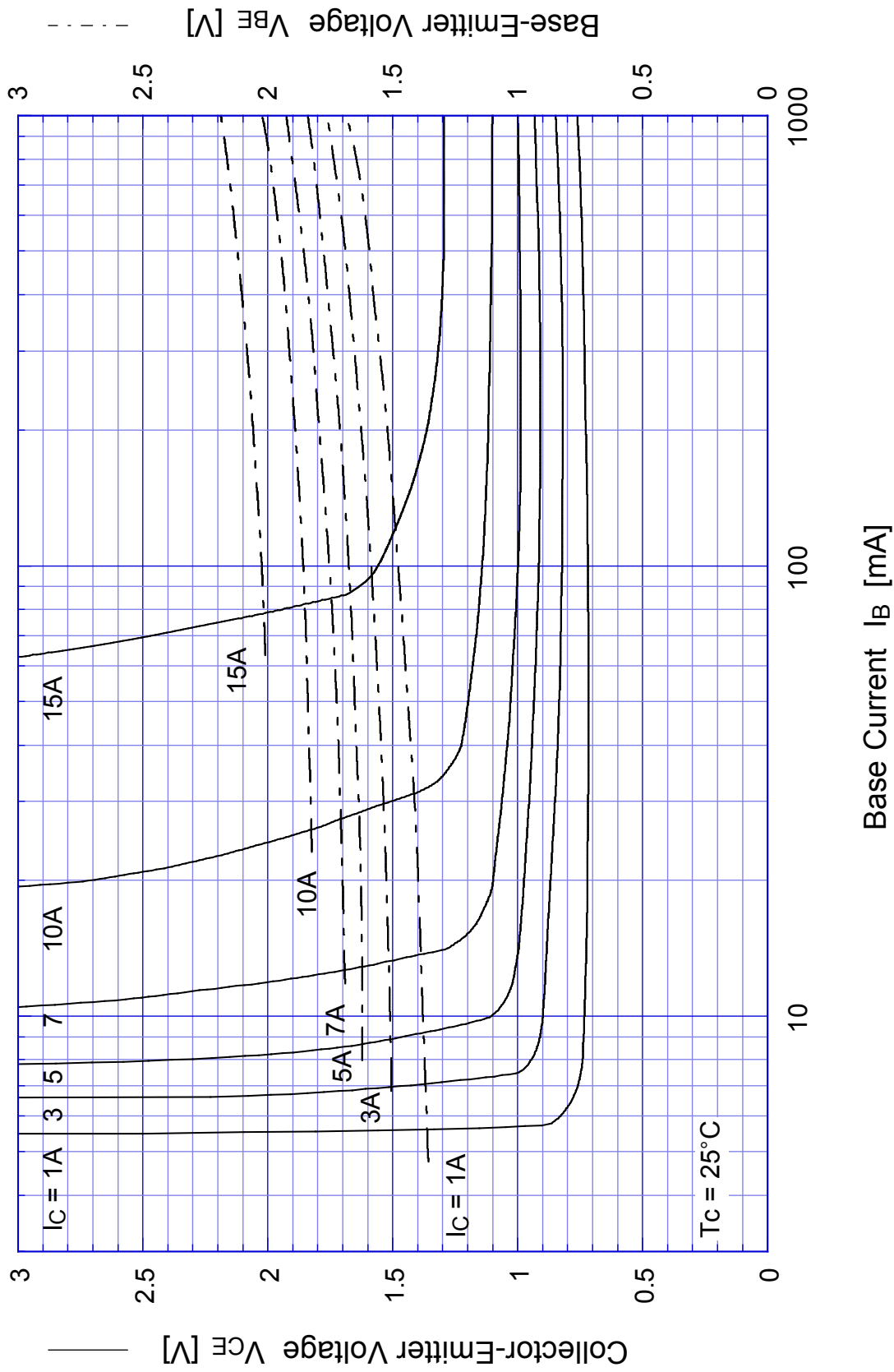
| Item                                    | Symbol               | Conditions  | Ratings | Unit |
|---|----------------------|---|---------|------|
| Collector to Emitter Sustaining Voltage | V <sub>CEO</sub>     | V <sub>CE</sub> (Clamp)   | Min 400 | V    |
| Collector Cutoff Current                | I <sub>CBO</sub>     | V <sub>CB</sub> = 500V  | Max 0.1 | mA   |
|   | I <sub>CEO</sub>     | V <sub>CE</sub> = 400V  | Max 0.1 |      |
| Emitter Cutoff Current                  | I <sub>EBO</sub>     | V <sub>EB</sub> = 12V   | Max 100 | mA   |
| DC Current Gain                         | h <sub>FE</sub>      | V <sub>CE</sub> = 2V, I <sub>C</sub> = 7A   | Min 150 |      |
| Collector to Emitter Saturation Voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> = 7A   | Max 1.5 | V    |
| Base to Emitter Saturation Voltage      | V <sub>BE(sat)</sub> | I <sub>B</sub> = 70mA   | Max 2.0 | V    |
| Thermal Resistance                      | θ <sub>JC</sub>      | Junction to case  | Max 2.5 | /W   |
| Transition Frequency                    | f <sub>T</sub>       | V <sub>CE</sub> = 10V, I <sub>C</sub> = 1A  | TYP 10  | MHz  |
| Turn on Time                            | t <sub>on</sub>      | I <sub>C</sub> = 7A<br>I <sub>B1</sub> = I <sub>B2</sub> = 70mA<br>R <sub>L</sub> = 10<br>V <sub>BB2</sub> = 4V | Max 2   | μs   |
| Storage Time                            | t <sub>s</sub>       |   | Max 15  |      |
| Fall Time                               | t <sub>f</sub>       |   | Max 15  |      |

# 2SD1795

$h_{FE} - I_C$

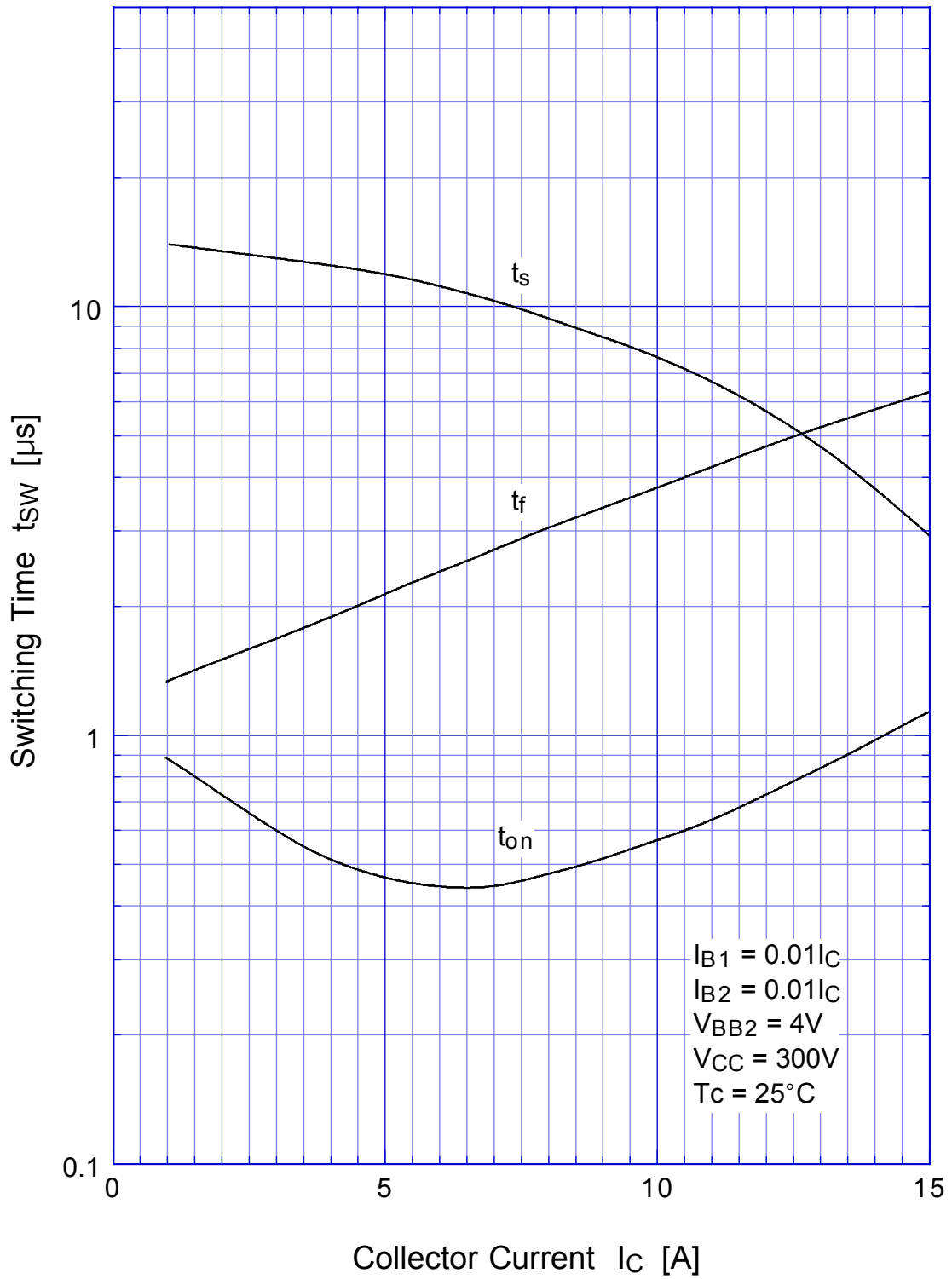


# 2SD1795 Saturation Voltage



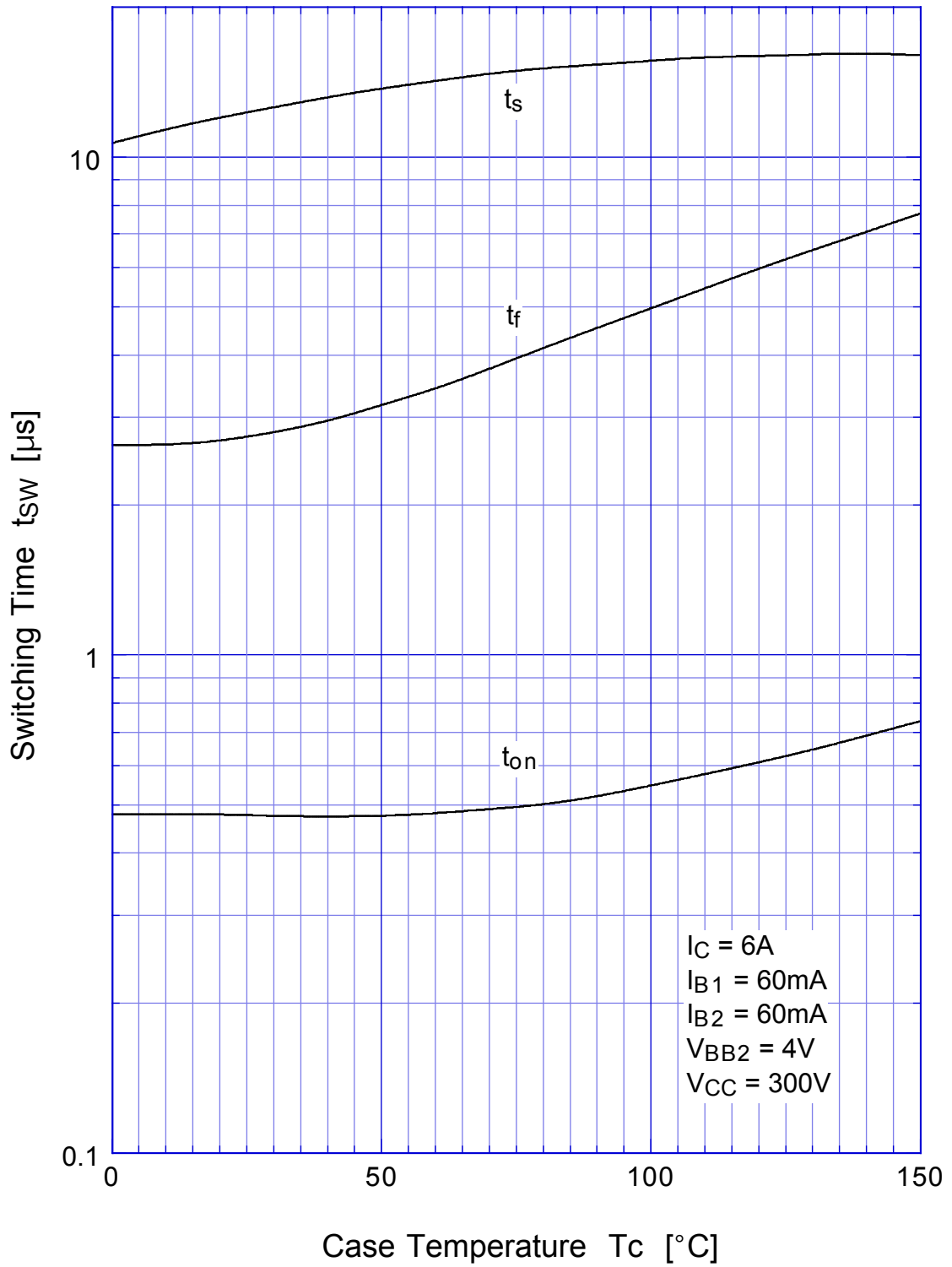
# 2SD1795

## Switching Time - $I_C$

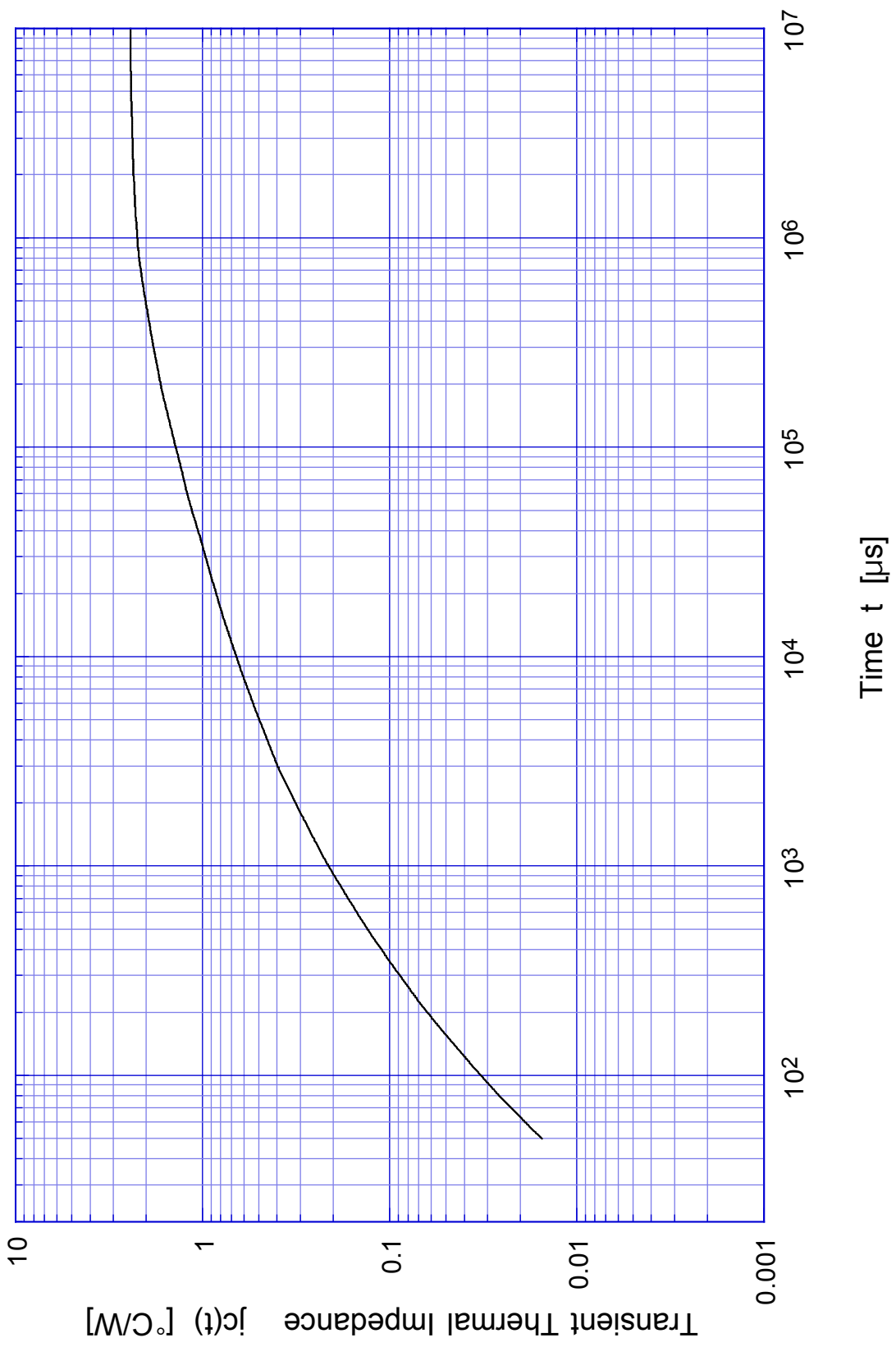


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## Switching Time - Tc

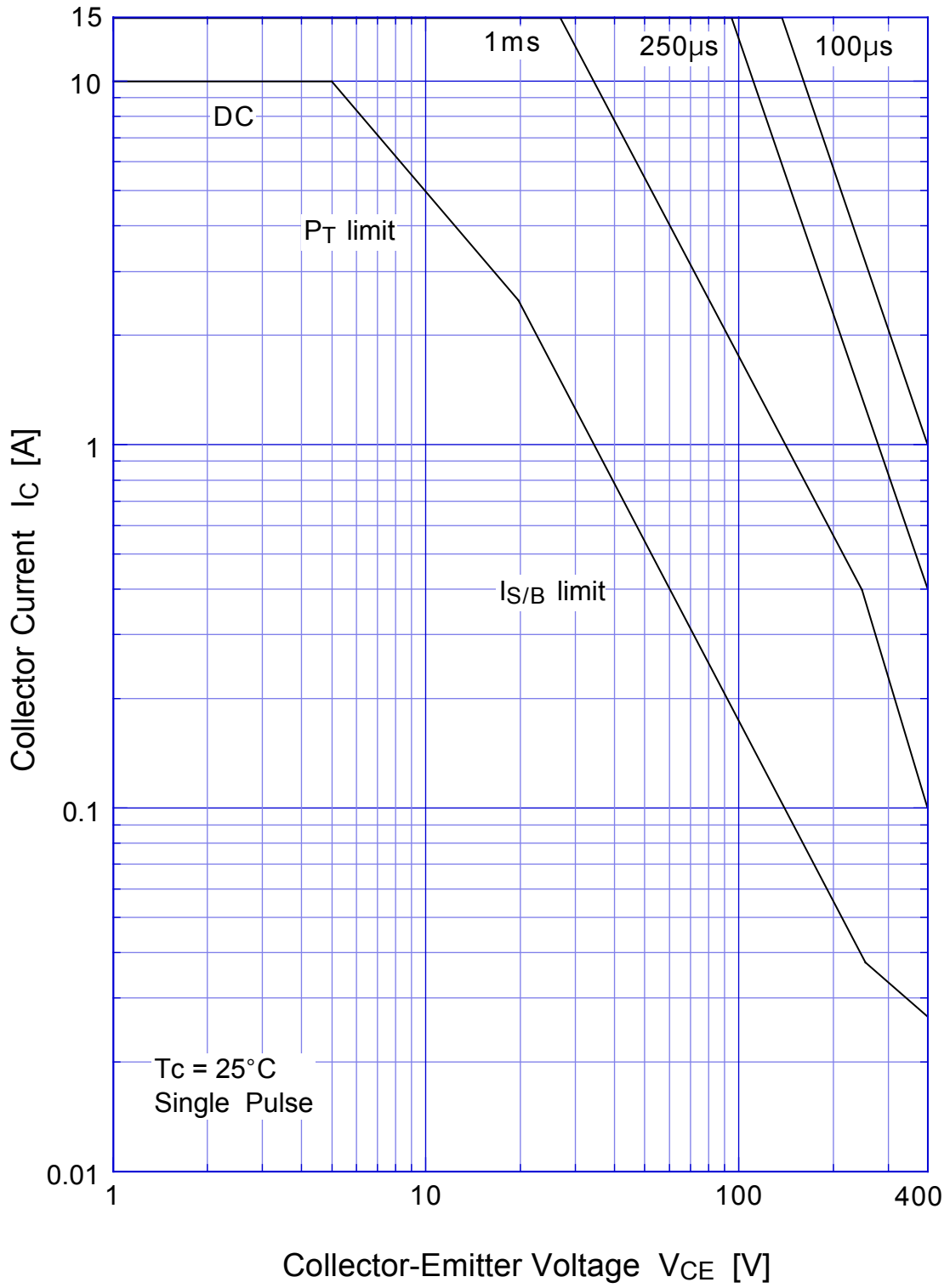


## 2SD1795 Transient Thermal Impedance

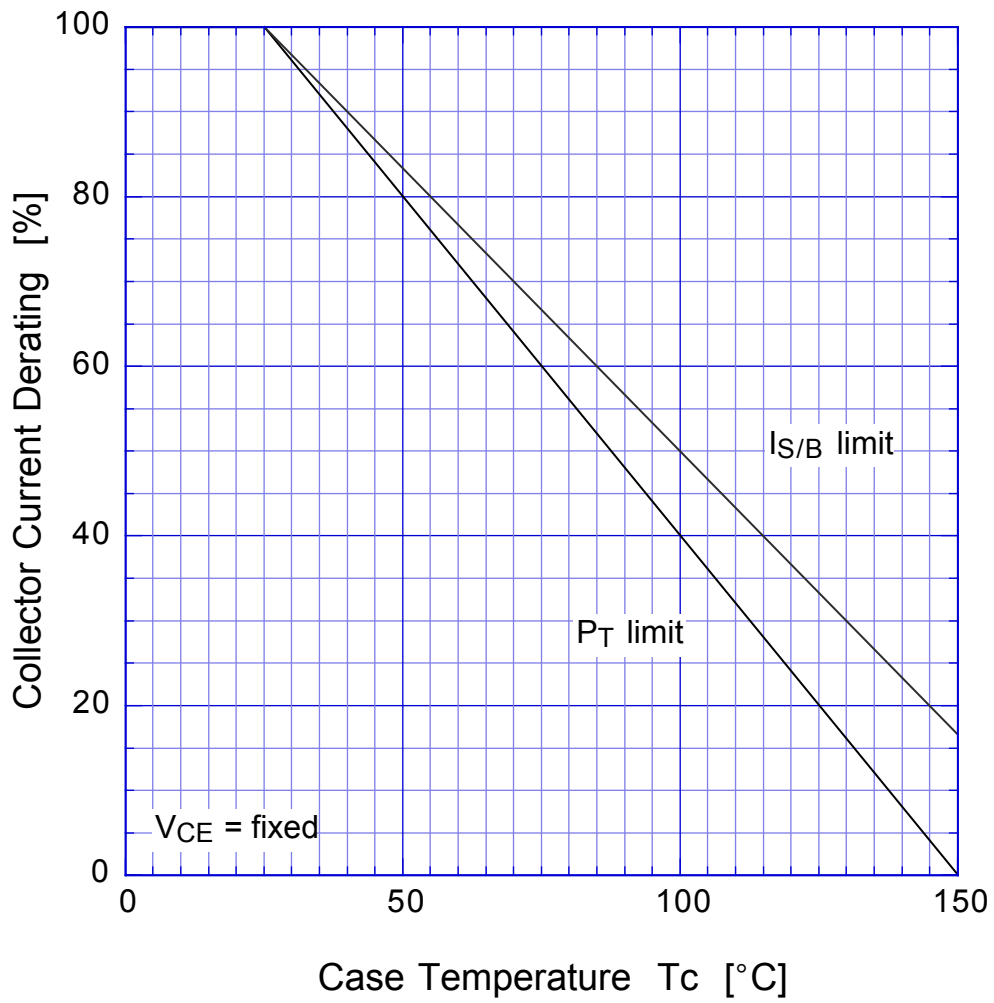


# 2SD1795

# Forward Bias SOA



# 2SD1795 Collector Current Derating





2SD1795

Reverse Bias SOA

